# **HEF4049B**

# Hex inverting buffers Rev. 9 — 18 November 2011

Product data sheet

#### 1. **General description**

The HEF4049B provides six inverting buffers with high current output capability suitable for driving TTL or high capacitive loads. Since input voltages in excess of the buffers' supply voltage are permitted, the buffers may also be used to convert logic levels of up to 15 V to standard TTL levels. Their guaranteed fan-out into common bipolar logic elements is shown in Table 3.

It operates over a recommended V<sub>DD</sub> power supply range of 3 V to 15 V referenced to V<sub>SS</sub> (usually ground). Unused inputs must be connected to V<sub>DD</sub>, V<sub>SS</sub>, or another input.

#### **Features and benefits** 2.

- Accepts input voltages in excess of the supply voltage
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

#### **Applications** 3.

- LOCMOS (Local Oxidation CMOS) to DTL/TTL converter
- HIGH sink current for driving two TTL loads
- HIGH-to-LOW level logic conversion

## Ordering information

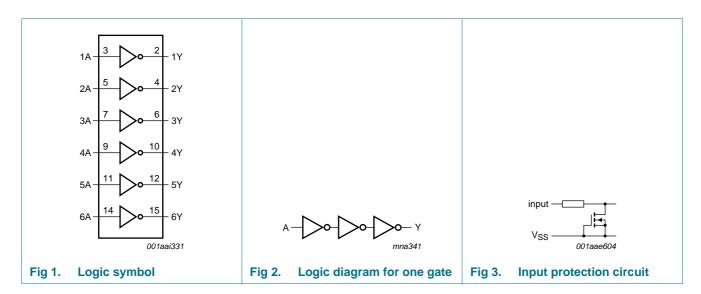
#### Table 1. **Ordering information**

All types operate from -40 °C to +85 °C.

Type number	Package	Package						
	Name	Description	Version					
HEF4049BP	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4					
HEF4049BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					

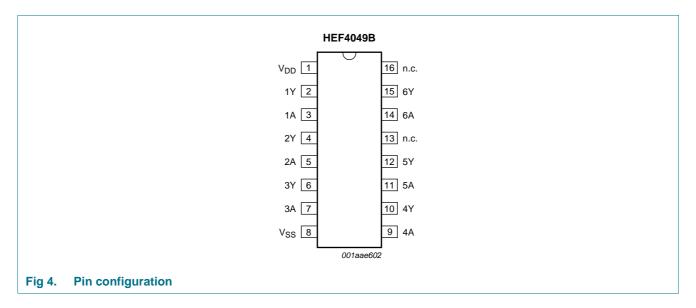


## 5. Functional diagram



## 6. Pinning information

## 6.1 Pinning



## 6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
$V_{DD}$	1	supply voltage
1Y to 6Y	2, 4, 6, 10, 12, 15	output

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Table 2. Pin description ... continued

Symbol	Pin	Description
1A to 6A	3, 5, 7, 9, 11, 14	input
V <sub>SS</sub>	8	ground supply voltage
n.c.	13, 16	not connected

# 7. Functional description

Table 3. Guaranteed fan-out

Driven element	Guaranteed fan-out
Standard TTL	2
74 LS	9
74 L	16

## 8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD}$	supply voltage		-0.5	+18	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{DD} + 0.5 \text{ V}$	-	±10	mA
VI	input voltage		-0.5	$V_{DD} + 0.5$	V
I <sub>OK</sub>	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{DD} + 0.5 \text{ V}$	-	±10	mA
I <sub>I/O</sub>	input/output current		-	±10	mA
I <sub>DD</sub>	supply current		-	50	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>amb</sub>	ambient temperature		-40	+85	°C
P <sub>tot</sub>	total power dissipation	$T_{amb}$ –40 °C to +85 °C			
		DIP16 package	[1] _	750	mW
		SO16 package	[2] _	500	mW
Р	power dissipation	per output	-	100	mW

<sup>[1]</sup> For DIP16 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

## 9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DD}$	supply voltage		3	-	15	V
$V_{I}$	input voltage		0	-	$V_{DD}$	V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+85	°C

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<sup>[2]</sup> For SO16 package: Ptot derates linearly with 8 mW/K above 70 °C.

 Table 5.
 Recommended operating conditions ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{DD} = 5 V$	-	-	3.75	μs/V
		V <sub>DD</sub> = 10 V	-	-	0.5	μs/V
		V <sub>DD</sub> = 15 V	-	-	0.08	μs/V

## 10. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$  V;  $V_I = V_{SS}$  or  $V_{DD}$  unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	T <sub>amb</sub> =	$T_{amb} = -40  ^{\circ}C$		T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = 85 °C	
				Min	Max	Min	Max	Min	Max	
$V_{IH}$	HIGH-level input voltage	$ I_{O}  < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$ I_{O}  < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V <sub>OH</sub>	HIGH-level output voltage	$ I_{O}  < 1 \mu A$	5 V	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
$V_{OL}$	LOW-level output voltage	I <sub>O</sub>   < 1 μA	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I <sub>OH</sub>	HIGH-level output current	$V_0 = 2.5 \ V$	5 V	-	-1.7	-	-1.4	-	-1.1	mΑ
		$V_0 = 4.6 \text{ V}$	5 V	-	-0.52	-	-0.44	-	-0.36	mΑ
		$V_0 = 9.5 V$	10 V	-	-1.3	-	-1.1	-	-0.9	mΑ
		$V_0 = 13.5 \text{ V}$	15 V	-	-3.6	-	-3.0	-	-2.4	mΑ
I <sub>OL</sub>	LOW-level output current	$V_0 = 0.4 \ V$	4.75 V	3.5	-	2.9	-	2.3	-	mΑ
		$V_0 = 0.5 \ V$	10 V	12.0	-	10.0	-	8.0	-	mΑ
		V <sub>O</sub> = 1.5 V	15 V	24.0	-	20.0	-	16.0	-	mΑ
l <sub>l</sub>	input leakage current	$V_{DD} = 15 \text{ V}$	15 V	-	±0.3	-	±0.3	-	±1.0	μΑ
I <sub>DD</sub>	supply current	$I_O = 0 A$	5 V	-	4.0	-	4.0	-	30	μΑ
			10 V	-	8.0	-	8.0	-	60	μΑ
			15 V	-	16.0	-	16.0	-	120	μΑ
Cı	input capacitance			-	-	-	7.5	-	-	pF

## 11. Dynamic characteristics

Table 7. Dynamic characteristics

 $V_{SS} = 0 \text{ V; } C_L = 50 \text{ pF; } t_f = t_f \le 20 \text{ ns; } T_{amb} = 25 \text{ °C; } unless \text{ otherwise specified.}$ 

	<del>-</del> • • • • •			•				
Symbol	Parameter	Conditions	$V_{DD}$	Extrapolation formula	Min	Тур	Max	Unit
t <sub>PHL</sub>	HIGH to LOW	nA to nY;	5 V	11 26 ns + (0.18 ns/pF)C <sub>L</sub>	-	35	70	ns
	propagation delay	see <u>Figure 5</u>	10 V	11 ns + (0.08 ns/pF)C <sub>L</sub>	-	15	30	ns
			15 V	9 ns + (0.05 ns/pF)C <sub>L</sub>	-	12	25	ns
t <sub>PLH</sub>	LOW to HIGH	nA to nY;	5 V	11 23 ns + (0.55 ns/pF)C <sub>L</sub>	-	50	100	ns
	propagation delay	n delay see <u>Figure 5</u>	10 V	14 ns + (0.23 ns/pF)C <sub>L</sub>	-	25	50	ns
			15 V	12 ns + (0.16 ns/pF)C <sub>L</sub>	-	20	40	ns
t <sub>THL</sub>	HIGH to LOW output	see Figure 5	5 V	11 3 ns + (0.35 ns/pF)C <sub>L</sub>	-	20	40	ns
	transition time		10 V	3 ns + $(0.14 \text{ ns/pF})C_L$	-	10	20	ns
			15 V	$2 \text{ ns} + (0.09 \text{ ns/pF})C_L$	-	7	14	ns
$t_{TLH}$	LOW to HIGH output	see Figure 5	5 V	10 ns + (1.00 ns/pF)C <sub>L</sub>	-	60	120	ns
	transition time		10 V	9 ns + (0.42 ns/pF)C <sub>L</sub>	-	30	60	ns
			15 V	6 ns + (0.28 ns/pF)C <sub>L</sub>	-	20	40	ns

<sup>[1]</sup> The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C<sub>L</sub> in pF).

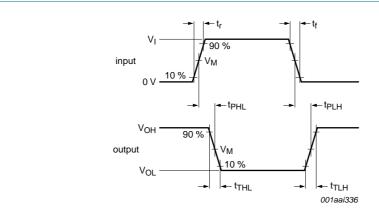
Table 8. Dynamic power dissipation P<sub>D</sub>

 $P_D$  can be calculated from the formulas shown.  $V_{SS} = 0$  V;  $t_r = t_f \le 20$  ns;  $T_{amb} = 25$  °C.

Symbol	Parameter	$V_{DD}$	Typical formula for P <sub>D</sub> (μW)	where:
$P_D$	dynamic power	5 V	$P_D = 2500 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}{}^2$	$f_i$ = input frequency in MHz;
	dissipation		$P_D = 11000 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$	f <sub>o</sub> = output frequency in MHz;
	15 V		$P_D = 35000 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	$C_L$ = output load capacitance in pF;
				$V_{DD}$ = supply voltage in V;
				$\Sigma(f_0 \times C_L)$ = sum of the outputs.

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#### 12. Waveforms



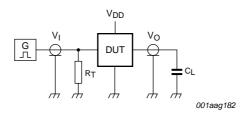
Measurement points are given in Table 9.

 $\ensuremath{V_{\text{OL}}}$  and  $\ensuremath{V_{\text{OH}}}$  are typical output voltage levels that occur with the output load.

Fig 5. Input (nA) to output (nY) propagation delays and transition times

Table 9. Measurement points

Input		Output				
V <sub>M</sub>	V <sub>I</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>		
0.5V <sub>DD</sub>	0 V to V <sub>DD</sub>	0.5V <sub>DD</sub>	0.1V <sub>DD</sub>	0.9V <sub>DD</sub>		



Test data is given in <u>Table 10</u>.

Definitions for test circuit:

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

Fig 6. Load circuitry for switching times

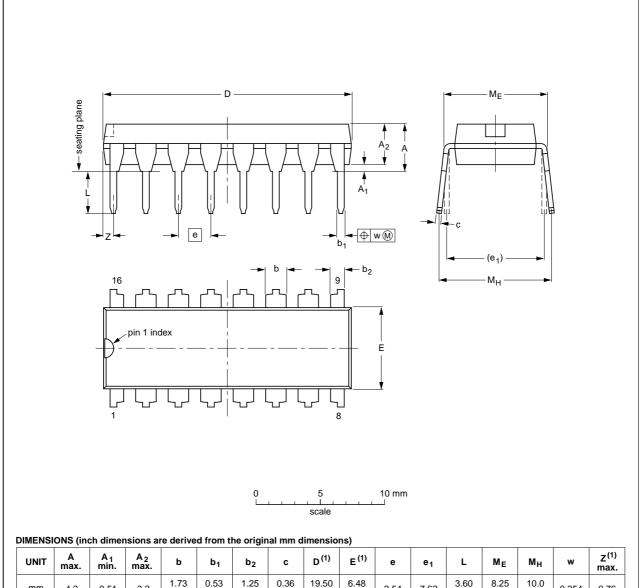
Table 10. Test data

Supply voltage	Input	Load		
	VI	$V_{M}$	t <sub>r</sub> , t <sub>f</sub>	CL
5 V to 15 V	$V_{DD}$	0.5V <sub>I</sub>	≤ 20 ns	50 pF

## 13. Package outline

#### DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT38-4						<del>95-01-14</del> 03-02-13

Fig 7. Package outline SOT38-4 (DIP16)

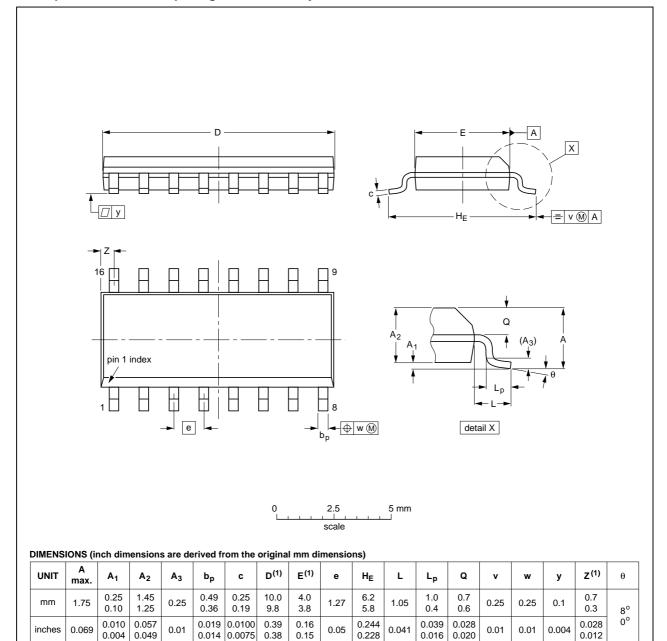
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#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19	

Fig 8. Package outline SOT109-1 (SO16)

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## 14. Abbreviations

#### Table 11. Abbreviations

Acronym	Description
DTL	Diode Transistor Logic
DUT	Device Under Test
LOCMOS	Local Oxidation CMOS
TTL	Transistor Transistor Logic

# 15. Revision history

#### Table 12. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4049B v.9	20111118	Product data sheet	-	HEF4049B v.8
Modifications:	• <u>Table 6</u> : I <sub>OH</sub>	minimum values changed t	o maximum	
	• <u>Table 11</u> : A	dded DUT		
HEF4049B v.8	20091202	Product data sheet	-	HEF4049B v.7
HEF4049B v.7	20090721	Product data sheet	-	HEF4049B v.6
HEF4049B v.6	20090325	Product data sheet	-	HEF4049B v.5
HEF4049B v.5	20081111	Product data sheet	-	HEF4049B v.4
HEF4049B v.4	20080704	Product data sheet	-	HEF4049B_CNV v.3
HEF4049B_CNV v.3	19950101	Product specification	-	HEF4049B_CNV v.2
HEF4049B_CNV v.2	19950101	Product specification	-	-

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.			
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.			
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